

ABSTRACTTHIN FILM TRANSISTOR SUBSTRATE COMPRISING PROTECTIVE
FILM AND METHOD FOR MANUFACTURING THE SAME

[Problem] To provide a thin film transistor substrate comprising a protective film, which can impart high driving stability.

[Means for Solution] A thin film transistor substrate comprising a thin film transistor and a protective film comprising a cured product of a siloxane composition, covering said thin film transistor, wherein the thin film transistor has a semiconductor layer made of an oxide semiconductor, and wherein the siloxane composition comprises polysiloxane, a fluorine-containing compound, and a solvent.

5 (Fig. 1)